

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a IITO220 internally insulated plastic package. This "series ET" triac triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers including microcontrollers. It is used in applications where "high junction operating temperature" capability is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with sensitive gate
- High T_{j(max)}
- Isolated mounting base with 2500 V (RMS) isolation
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only

3. Applications

- Electronic thermostats (heating and cooling)
- Motor Controls
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating	·				
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 120 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	10	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	-	100	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	110	А
Tj	junction temperature		-	-	150	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics		,			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	0.5	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	0.5	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _i = 25 °C; <u>Fig. 7</u>	0.5	-	10	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	15	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
Dynamic	characteristics		,			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	-	-	V/µs
dI _{com} /dt rate of change of commutating current		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	2	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 10 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	3.5	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	5	-	-	A/ms

5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	Ν
2	T2	main terminal 2	$2 \bigcirc 4$	
3	G	gate		sym051
mb	n.c.	mounting base; isolated		
			$ \begin{array}{c} \left\langle \right\rangle \left\langle \right\rangle \left\langle \right\rangle \left\langle \right\rangle \\ \left\langle \right$	

6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BTA410Y-600ET	IITO220	BTA410Y-600ET,127	Tube	50	SOT78D (A)	10-July-2007		
					IITO220P (P)	31-Mar-2023		

7. Marking

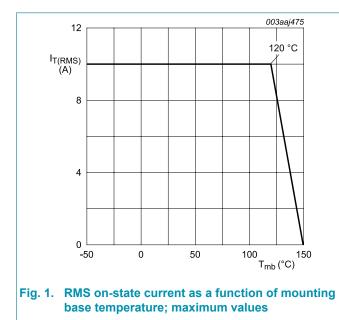
Table 4. Marking codes						
Type number	Marking codes					
	Assembly factory: A	Assembly factory: P				
BTA410Y-600ET	BTA410Y 600ET PJAxxxx xx	BTA410Y 600ET PJPxxxx xx				

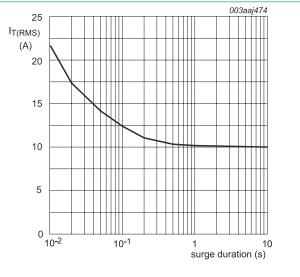
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	М	in Ma	x Unit
V_{DRM}	repetitive peak off-state voltage		-	60	0 V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 120 °C; <u>Fig 1; Fig 2; Fig 3</u>	-	10	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	-	10	0 A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	11(A C
l ² t	I ² t for fusing	t _p = 10 ms; sine wave	-	50	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 0.2 A	-	10	0 A/µs
I _{GM}	peak gate current		-	2	A
P _{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	5 W
T _{stg}	storage temperature		-4	0 12	5 °C
Tj	junction temperature		-	15	0°C





f = 50 Hz; T_{mb} = 120 °C
 Fig. 2. RMS on-state current as a function of surge duration; maximum values

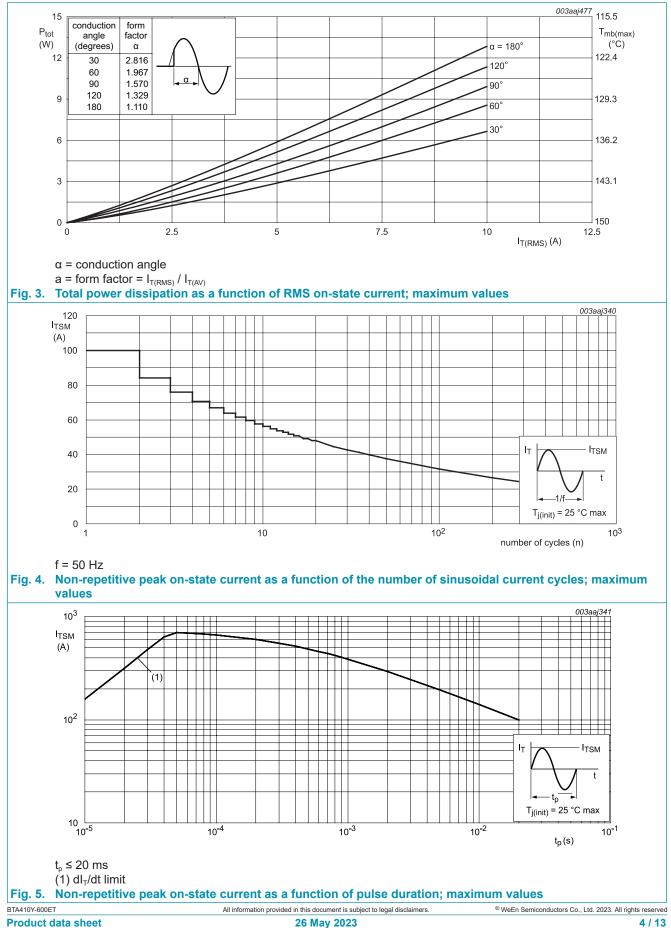
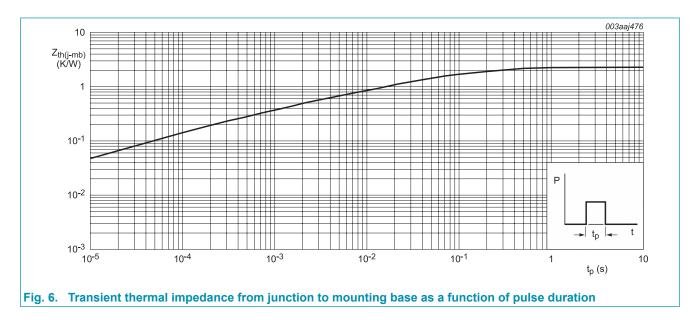


Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	full cycle; <u>Fig. 6</u>		-	-	2.3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W

9. Thermal characteristics



10. Isolation characteristics

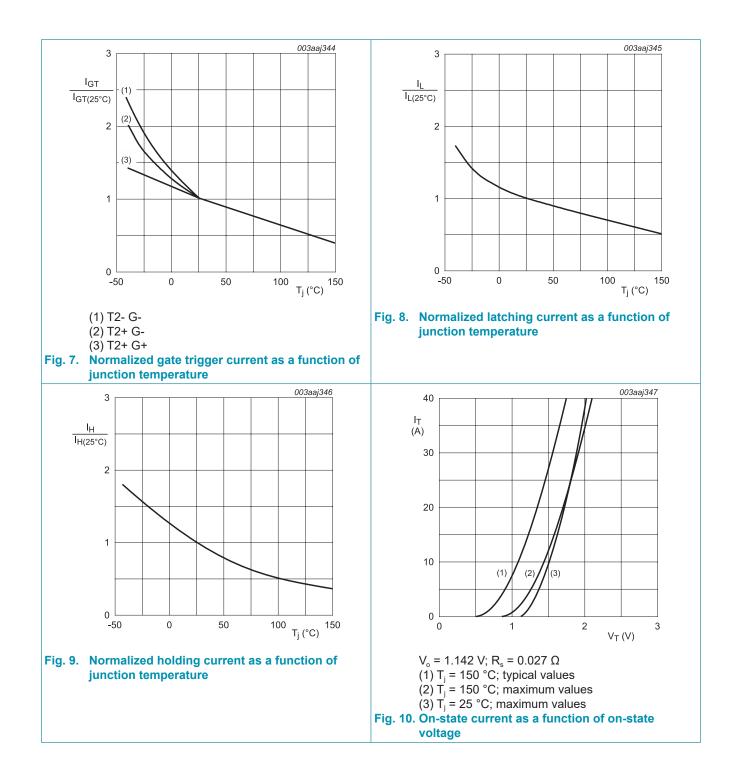
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _{mb} = 25 °C	-	-	2500	V
C_{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T_{mb} = 25 °C	-	10	-	pF

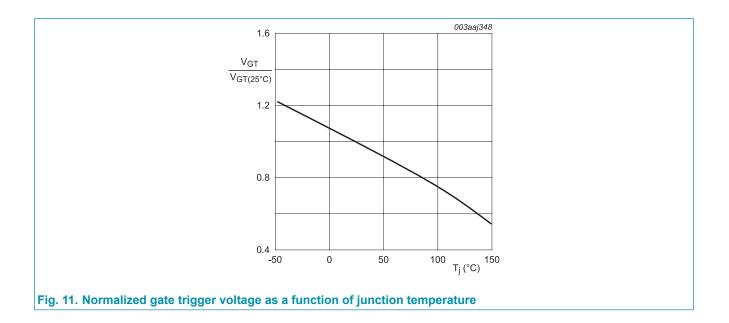
11. Characteristics

	haracteristics			_		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 7</u>	0.5	-	10	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 7	0.5	-	10	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; Fig. 7	0.5	-	10	mA
I _L	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	-	25	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8	-	-	30	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	25	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	15	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
V _{GT} gate trigg	gate trigger voltage	$V_{\rm D}$ = 12 V; T _j = 25 °C; Fig. 11	-	0.7	1	V
		V _D = 400 V; T _j = 150 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	0.4	2	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 20 \text{ V/}\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	2	-	-	A/ms
		V_{D} = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 10 V/µs; (snubberless condition); gate open circuit	3.5	-	-	A/ms
		V_{D} = 400 V; T _j = 150 °C; I _{T(RMS)} = 10 A; dV _{com} /dt = 1 V/µs; (snubberless condition); gate open circuit	5	-	-	A/ms

3Q Hi-Com Triac

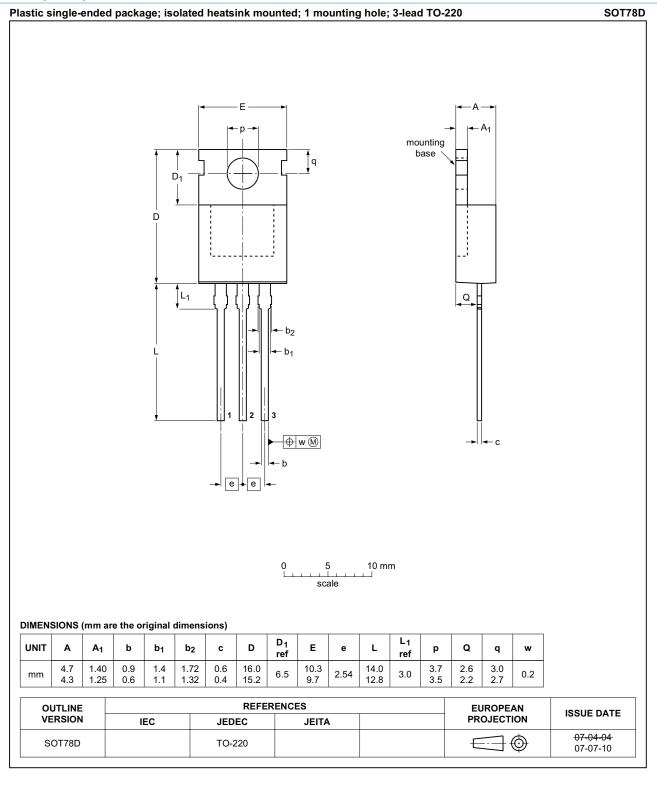
BTA410Y-600ET



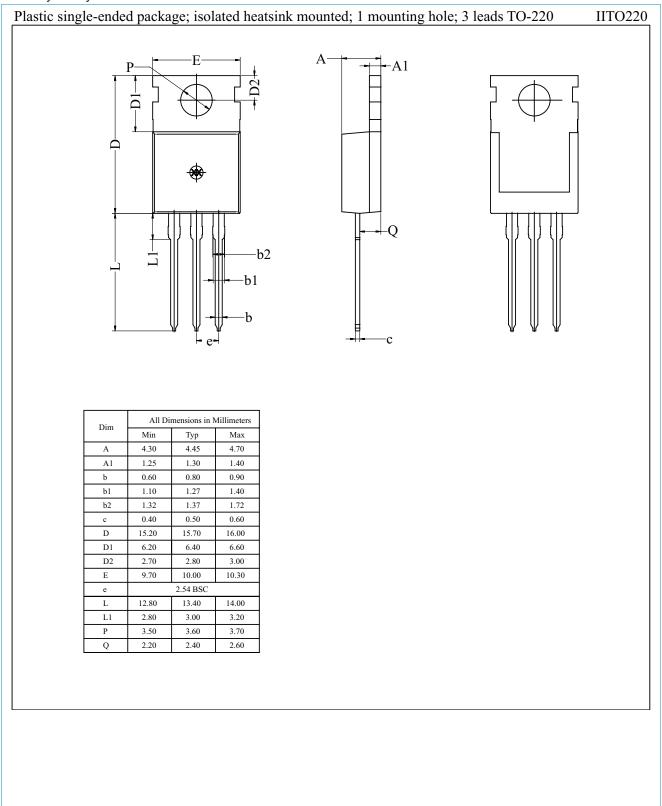


12. Package outline

Assembly factory: A



Assembly factory: P



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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14. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Isolation Characteristics	5
11. Characteristics	6
12. Package outline	9
13. Legal information	11
14. Contents	13

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